

2025 EUVL and Source Workshop

June 21-22 (Online Only Short Courses)

June 23 - June 26, 2025 (Held In-Person only at MIT Lincoln Lab)



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DAY 1, Monday, 23 June, 2025: Blue-X Technical Working Group (TWG) Meeting

| Start | Title | Presenter |
|---|---|---|
| 8:30 | <i>Breakfast, Coffee and Check-in</i> | |
| Session 1: Blue-X Opening Session | | Session Chair: Mordy Rothschild, MIT LL |
| 9:30 | Announcements, Program and Membership Updates | Vivek Bakshi, EUV Litho |
| Session 2: Resist Sub TWG Presentations | | Session Chair: Mordy Rothschild, MIT LL |
| 9:50 | Review of LBNL exposure results of June 13 | Dario Goldfarb, IBM |
| 10:05 | Resist Testing at PSI | Iacopo Mochi, PSI |
| 10:15 | Resist Testing at PAL | Sangsul Lee, POSTECH |
| 10:25 | Resist Testing at BNL | Nikhil Tiwale, BNL |
| 10:35 | <i>Break</i> | |
| Session 3: Optics and Mask Sub TWG Updates | | Session Co-Chairs: Meng Lee (Veeco) and Marcelo Ackermann, Univ of Twente |
| 10:50 | Imaging and Optical Design Sub TWG Update | Gregg Gallatin, Applied Math and Allen Gabor, IBM / EUV Tech |
| 11:10 | ML Optics Sub TWG: ML Round Robin Update | Marcelo Ackermann, Univ of Twente |
| 11:30 | Non ML Optics Sub TW Update | Mark Schattenburg, MIT |
| 11:40 | Mask Sub TWG Update | Meng Lee, Veeco |
| 12:00 | <i>Lunch</i> | |
| Session 4: Metrology Sub TWG Update | | Session Co-Chairs: Isvar Cordova (NIST) and Muharrem Bayraktar, Univ of Twente |
| 1:00 | Flying Circus Program Update | Muharrem Bayraktar, Univ of Twente |
| 1:10 | Preparing for the future of EUVL metrology at NIST, the U.S. National Metrology Institute | Rob Vest, NIST |
| 1:20 | TBA | Stephanie Moffitt |
| Session 5: Source Sub TWGs Update | | Session Co-Chairs: Oscar Versolato, ARCNL and James Colgan, LANL |
| 1:30 | The Must Light Source | Yosuke Honda, KEK |
| 1:40 | xLight FEL Status Update | Kevin Heidrich, xLight |
| 1:50 | Advanced Fusion Source Status Update | William Joyce, AFS |
| 2:00 | EUV and plasma sources using high energy solid state $\lambda \approx 2 \mu\text{m}$ laser drivers | Jackson Williams, LLNL |
| 2:10 | Solid state laser drivers for EUV plasma sources | Peter Moulton, MIT LL |
| 2:20 | Plasma Simulation for Blue-X Sources | Paul Chesler, MIT LL |
| 2:30 | Plasma Simulation for Ne Sources for 6.7 nm emission | Alessandro Ruocco, FS Dynamics |
| 2:40 | Liquid Nitrogen Droplets for Blue-X Sources | Tommy Sebastian, MIT LL |
| 2:50 | Overview of the fundamental atomic data required for modeling the emission from Blue-X ions of interest | James Colgan, LANL |
| 3:00 | Plasma Sources sub TWG Update | Takeshi Higashiguchi, Utsunomiya University |
| 3:15 | <i>Break</i> | |
| Session 6: Blue-X Closing Session | | Session Chair: Vivek Bakshi, EUV Litho |
| 3:30 | Potential Stoplight Charts for Blue-X: Presentation and Discussion | Allen Gabor, IBM |
| 4:10 | <i>Break</i> | |
| 4:30 | Joint Reception with 2025 EUVL and Source Workshop Attendees | |
| 6:00 | Buses take attendees back to their hotels | |



DAY 2, Tuesday, 24 June, 2025: 2025 EUVL and Source Workshop

| Start | Title | Presenter |
|--|--|---|
| 8:30 | <i>Breakfast, Coffee and Check-in</i> | |
| Session 1: Keynote 1 | | Session Chair: Mordy Rothschild, MIT LL |
| 9:00 | Welcome and Announcements | Vivek Bakshi, EUV Litho and Mordy Rothschild, MIT LL |
| 9:15 | Update on High-NA EUV in process technology development | Steven Carson, Intel |
| 9:45 | IBM Lithography Roadmap and Need for Future Lithography Tools | Allen Gabor, IBM |
| 10:15 | Microelectronics Development at Lincoln Laboratory | Mark Gouker, MIT LL |
| 10:45 | <i>Break</i> | |
| Session 2: Mask 1 | | Session Co-Chairs: Marcus Benk, CXRO and Matt Hettermann, EUV Tech |
| 11:00 | EUV Absorber Sidewall Metrology with EUV Scatterometry | Peter Dudenas, EUV Tech |
| 11:15 | Hyper-NA EUV Imaging, and Beyond | Marcus Benk, CXRO |
| 11:30 | HVM-ready EUV zoneplate microscopy for mask defect review | Matt Hetterman, EUV Tech |
| 11:45 | <i>Lunch</i> | |
| Session 3: Mask 2 | | Session Co-Chairs: Ron Levi, Corning and Katrina Rook, Veeco |
| 12:45 | EXTREME ULE® for EUV Lithography reticles | Roni Levi, Corning |
| 1:00 | Ion Implantation for Improved Etching and Optical Performance in Next-Generation EUV Mask | Yunsoo Kim, Hanyang University |
| 1:15 | Holistic design for EUV blanks beyond 1.X nm node | Ikebe Yohei, Hoya |
| 1:30 | High NA EUV design to mask stitching enablement | Kevin Lucas, Synopsys |
| 1:45 | Advanced Ion Source & Target Developments for EUV Mask Multilayer Deposition | Katrina Rook, Veeco |
| 2:00 | <i>Break</i> | |
| Session 4: Metrology | | Session Chair: Ahmed Diallo, PPPL |
| 2:15 | High Resolution Imaging and Spectrographic Instruments for 1-10 nm X-ray Astrophysics | Mark Schattenburg, MIT |
| 2:30 | Absolute Traceable Electrical Substitution Radiometers for EUV Wavelengths and Beyond | Brian Simonds, NIST |
| 2:45 | Synthesis and metrology of Cr/Sc-based multilayer mirrors for the water window | Franck Delmotte, Université Paris-Saclay |
| Session 5: Modeling (Session Dedicated to the Memory of Howard Scott) | | Session Co-Chairs: Igor Golovkin, Prism Computations and James Colgan, LANL |
| 3:00 | In memory of Howard Scott | James Colgan, LANL |
| 3:05 | Effective temperature approximations for use in modeling non-LTE tin plasmas | James Colgan, LANL |
| 3:20 | Examining Kinetic Plasma Behavior in EUVL Sources with Particle-In-Cell Simulations | Kirill Lezhnin, PPPL |
| 3:35 | Plasma Simulations of EUV/x-ray Sources: Radiation Transport and Atomic Physics Models | Igor Golovkin, Prism Computations |
| 3:50 | Atomic model to model EUV emission spectrum and to produce the opacity table of tin | Akira Sasaki, QST |
| 4:05 | <i>Break</i> | |
| Session 6: Sources 1 | | Session Co-Chairs: Jens Brunne, Trumpf and Hakaru Mizoguchi, Kyushu University |
| 4:20 | The path towards 1.5kW EUV with the CO2 drive laser | Jens Brunne, Trumpf |
| 4:35 | Increment of EUV radiation and reduction of ion energy of laser-produced Sn EUV-light-source plasmas by controlling initial plasma structure using multiple pre-pulse laser irradiations | Kentaro Tomita, Hokkaido University |
| 4:50 | Plasma Dynamics and Future of LPP-EUV Source for Semiconductor Manufacturing IV | Hakaru Mizoguchi, Kyushu University |
| 5:05 | Diagnostics of Laser-assisted Discharge Tin Plasma EUV source using collective Thomson scattering | Hideyuki Sera, Ushio |
| 5:20 | <i>Break</i> | |
| Session 7: Poster Session | | Session Chair: Vivek Bakshi, EUV Litho |
| 7:00 | <i>Buses depart for hotels</i> | |



DAY 3, Wednesday, 25 June, 2025: 2025 EUVL and Source Workshop

| Start | Title | Presenter |
|---|---|---|
| 8:30 | <i>Breakfast, Coffee and Check-in</i> | |
| Session 8: Keynote 2 | | Session Chair: Carrie Huguenin, MIT LL |
| 8:55 | Welcome and Announcements | Vivek Bakshi, EUV Litho and Mordy Rothschild, MIT LL |
| 9:00 | Research & roadmap for future sources of EUV light and beyond (BEUV) | Oscar Versolato, ARCNL |
| 9:30 | We Can Make a Difference – How to Promote Women in Technology | Debbie Gustafson, Energetiq |
| 10:00 | Development of Next-Generation Semiconductor Process Technologies for EUV and BEUV under Japan’s “K Program” for Economic Security by JST | Junji Yumoto, University of Tokyo |
| 10:30 | <i>Break</i> | |
| Session 9: Resist and Patterning 1 | | Session Co-Chairs: Alex Robinson, IM and Anuja DeSilva, Lam |
| 10:45 | The Multi-Trigger Resist - EUV Performance Update | Alex Robinson, IM |
| 11:00 | Recent Developments and an Unexpected Discovery in Our Tin-Based Inorganic Molecular Resists for EUV Lithography | Hyun-Dam Jeong, Chonnam National University |
| 11:15 | EUV photoresists with controlled sequences lead to improved stochastics and the discovery of a novel patterning mechanism | Chenyun Yuan, Cornell |
| 11:30 | Next-Generation EUV Double Amplification Photoresists From Acid-Catalyzed Chain Unzipping | Rachel Snyder, Dupont |
| 11:45 | EUV NTD-CAR performance toward high-NA EUVL | Nishiki Fujimaki, Fujifilm |
| 12:00 | Dry Resist Patterning Readiness Towards High NA EUV Lithography | Anuja DeSilva, Lam |
| 12:15 | <i>Lunch</i> | |
| Session 10: Sources 2 | | Session Co-Chairs: Jochen Viekers, ILT and Takeshi Higashiguchi, Utsunomiya University |
| 1:15 | Efficient EUV/B-EUV sources by laser irradiation schemes | Takeshi Higashiguchi, Utsunomiya University |
| 1:30 | A compact laser-driven short-wavelength radiation source | Yusuke Teramoto, Ushio |
| 1:45 | SXR development for metrology, inspection, and process control using a discharge-produced plasma source | David Reisman, Energetiq |
| 2:00 | Laser-driven x-ray generation for industrial applications | Jocken Vieker, ILT |
| 2:15 | <i>Break</i> | |
| Session 11: Sources 3 | | Session Co-Chairs: Peter Moulton, MIT LL and Henry Kapteyn, K&M Labs |
| 2:30 | 2 μ m fiber laser systems for next generation EUV plasma sources | Christian Gaida, Active Fiber Systems GmbH |
| 2:45 | Why High-Order Harmonic Generation Is the Optimal Source Solution for EUV Mask Review Systems | Dong Gun Lee, E-Sol |
| 3:00 | High-Harmonic Generation driven Extreme-Ultraviolet Scatterometry for Nanostructure Characterization | Peter Kraus, ARCNL |
| 3:15 | High repetition rate, high average power XUV sources based on High Harmonic Generation | Bastian Manschwetus, Class 5 Photonics |
| 3:30 | Nanoscale Metrologies using Coherent EUV Sources | Henry Kapteyn, K&M Labs |
| 4:00 | <i>Break and Buses Depart for Site Tours and Hotels: Energetiq Reception or MIT. Nano Tour</i> | |

| Start | Title | Presenter |
|---|---|---|
| 8:30 | <i>Breakfast, Coffee and Check-in</i> | |
| Session 12: Keynote 3 | | Session Chair: Mordy Rothschild, MIT LL |
| 8:55 | Welcome and Announcements | Vivek Bakshi, EUV Litho and Mordy Rothschild, MIT LL |
| 9:00 | EUV multilayer optimization for next-generation EUVL - 13.5nm/11.3nm high-NA and 6.6nm/WW opportunities | Bruce Smith, RIT |
| 9:30 | EUV and Non-EUV Based Lithography R&D to Extend Semiconductor Device Scaling and Improve Manufacturing Efficiency | Robert Chau, Natcast |
| 10:00 | <i>Break</i> | |
| Session 13: Supplier Showcase | | Session Co-Chairs: Jacqueline van Veldhoven, TNO and Meng Lee, Veeco |
| 10:15 | Cost- Effective EUV Light Sources for High-Volume Manufacturing | Henry Chou, Energetiq |
| 10:30 | Studying the interaction of EUV and plasma with scanner construction materials | Jacqueline van Veldhoven, TNO |
| 10:45 | Applications of EUV Metrology Tools | Matt Hettermann, EUV Tech |
| 11:00 | Tools and solutions for actinic EUV metrology | Andreas Biermanns – Foeth, Research Instruments |
| 11:15 | 2025 EUV and Source Workshop Invited Talk (Tentative Title) | Meng Lee, Veeco |
| 11:30 | <i>Lunch</i> | |
| Session 14: Resist and Patterning 2 | | Session Co-Chairs: Ralph Dammel, Merck and Nikhil Tiwale, BNL |
| 12:45 | Estimation of Resist Photospeeds for Blue-X Wavelengths | Ralph Dammel, Merck/EMD Electronics |
| 1:00 | Advancing EUV Photoresist Development: High-Throughput Screening of Electron-Induced Chemical Transformations | Oleg Kostko, CXRO |
| 1:15 | Isomorphic molecular control of Sb based inorganic EUV photoresist for optimized photosensitivity and stability | Myung-Gil Kim, Sungkyunkwan University |
| 1:30 | Organic-Inorganic Hybrid EUV Photoresists Derived from Atomic Layer Deposition Techniques | Chang-Yong Nam, Brookhaven National Lab |
| 1:45 | <i>Break</i> | |
| Session 15: Optics (Session dedicated to the memory of Sascha Migura, Zeiss) | | Session Co-Chairs: Torsten Feigl, optiXfab and Marcelo Ackermann, University of Twente |
| 2:00 | In Memory of Sascha Migura | Heiko Feldmann, Zeiss |
| 2:05 | Beyond One-Size-Fits-All: Tailoring EUV (and BEUV) Optics for HVM Efficiency | Donic Flagello, Nikon Research |
| 2:20 | Hyper-NA: an EUV system with a numerical aperture of at least 0.75 | Michael Patra, Carl Zeiss |
| 2:35 | 2025 EUV and Source Workshop Invited Talk (Tentative Title) | Torsten Feigl, optiXfab |
| 2:50 | 2025 EUV and Source Workshop Invited Talk (Tentative Title) | Marcelo Ackermann, University of Twente |
| 3:05 | Advanced Blue-X Multilayer Coating Designs Strategies | Vladimir Liberman, MIT LL |
| 3:20 | <i>Break</i> | |
| Session 16: Resist and Patterning 3 | | Session Co-Chairs: Sascha Brose, RWTH and Iacopo Mochi, PSI |
| 3:35 | Lab-based EUV interference lithography for large-area nanopatterning towards sub-10 nm resolution | Sascha Brose, RWTH |
| 3:50 | Replacing EUV with X-ZPAL | Hank Smith, MIT |
| 4:05 | Advanced Coater/developer Technologies for High-NA EUV Lithography | Congque Dink, TEL |
| 4:20 | EUV Lithography at The Center for X-Ray Optics | Bruno LaFontaine, CXRO |
| 4:35 | Development of a Next-Generation Interference Lithography End Station at the Swiss Light Source | Iacopo Mochi, PSI |
| 4:50 | Amorphous Zeolitic imidazolate Framework (aZIF) Films for Electron Beam, Extreme UV, and Beyond Extreme UV Lithography Applications | Michael Tsapatsis, John Hopkins University |
| 5:05 | Announcements | |
| 5:20 | <i>Workshop Dinner</i> | |
| 7:00 | <i>Buses depart for hotels</i> | |